BC856AFSWQ - BC857CFSWQ

PNP SMALL SIGNAL TRANSISTOR IN DFN1412-3/SWP

Description

The BC856AFSWQ-7, BC856BFSWQ-7, BC857AFSWQ, BC857BFSWQ, and BC857CFSWQ bipolar junction transistors (BJT) are designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > 65V (BC856)
- BV_{CEO} > 45V (BC857)
- I_C = 100mA High Continuous Collector Current
- Low-Profile 0.6mm High Package for Thin Applications
- Sidewall Tin Plating for Wettable Flanks in AOI
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BC856AFSWQ-7, BC856BFSWQ-7, BC857AFSWQ, BC857BFSWQ, and BC857CFSWQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities. https://www.diodes.com/quality/product-definitions/**

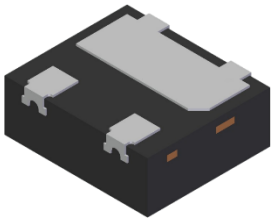
Mechanical Data

- Package: U-DFN1412-3/SWP (Type A)
- Package Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.0050 grams (Approximate)

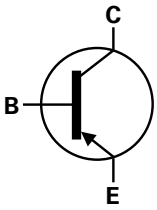
Application

- Switching and amplification

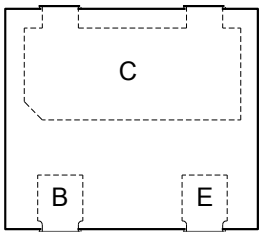
U-DFN1412-3/SWP



Bottom View



Device Symbol



Top View
Pin-Out

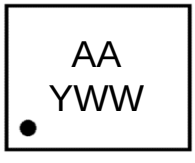
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty	Carrier
BC856AFSWQ-7	U-DFN1412-3/SWP (Type A)	4E	7	8	5,000	Reel
BC856BFSWQ-7	U-DFN1412-3/SWP (Type A)	4F	7	8	5,000	Reel
BC857AFSWQ-7	U-DFN1412-3/SWP (Type A)	4G	7	8	5,000	Reel
BC857BFSWQ-7	U-DFN1412-3/SWP (Type A)	4H	7	8	5,000	Reel
BC857CFSWQ-7	U-DFN1412-3/SWP (Type A)	4J	7	8	5,000	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

U-DFN1412-3/SWP



AA = Product type Marking Code
YWW = Date Code Marking
Y = Last Digit of Year (ex: 4 = 2024)
WW = Week Code 01 to 53

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Collector-Base Voltage	BC856	V_{CBO}	-80	V
	BC857		-50	
Collector-Emitter Voltage	BC856	V_{CEO}	-65	V
	BC857		-45	
Emitter-Base Voltage		V_{EBO}	-6	V
Continuous Collector Current		I_C	-100	mA
Peak Pulse Collector Current		I_{CM}	-200	mA
Peak Base Current		I_{BM}	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	450	mW
	(Note 6)		1.25	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	278	°C/W
	(Note 6)		100	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Charged Device Model	ESD CDM	1000	V	C3

Notes:
5. For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note (5), except the device is mounted with 1-inch square pad and 2oz copper.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

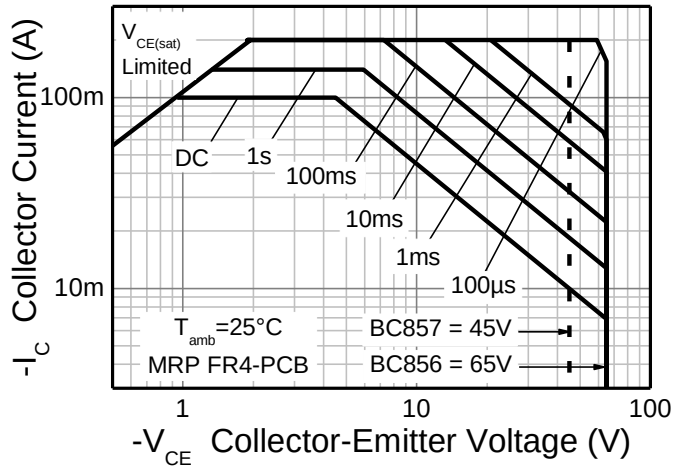


Fig.1 Safe Operating Area

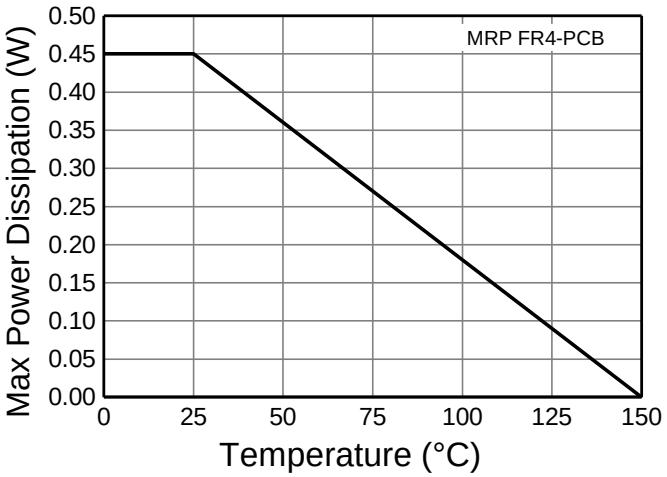


Fig.2 Derating Curve

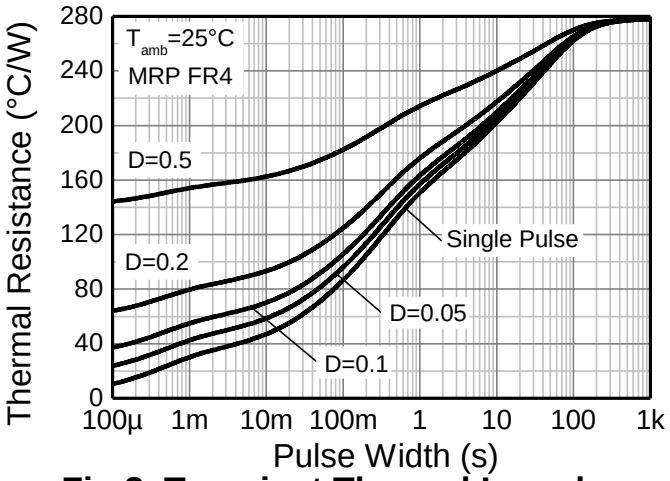


Fig.3 Transient Thermal Impedance

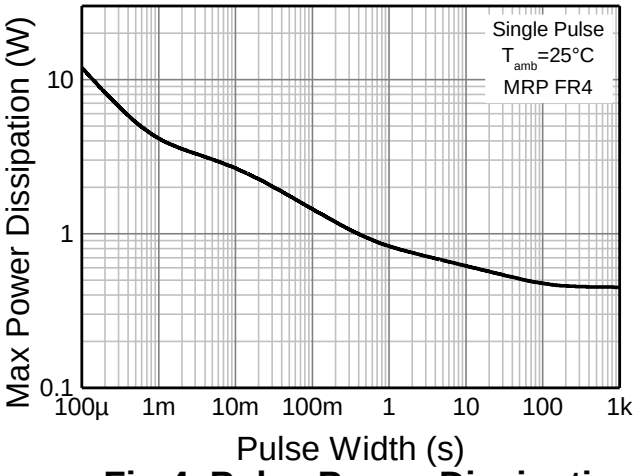


Fig.4 Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BC856	BV_{CBO}	-80	—	—	V	I_C = -100µA
	BC857		-50				
Collector-Emitter Breakdown Voltage (Note 8)	BC856	BV_{CEO}	-65	—	—	V	I_C = -10mA
	BC857		-45				
Emitter-Base Breakdown Voltage		BV_{EBO}	-7	—	—	V	I_E = -100µA
Collector-Base Cutoff Current		I_{CBO}	—	—	-15	nA	V_{CB} = -30V, I_E = 0
			—	—	-5	µA	V_{CB} = -30V, I_E = 0, T_A = +150°C
Emitter-Base Cutoff Current		I_{EBO}	—	—	-100	nA	V_{EB} = -5.6V, I_C = 0
DC Current Gain	BC856A BC857A	h_{FE}	125	—	250	—	V_{CE} = -5V, I_C = -2mA
	BC856B BC857B		220	—	475		V_{CE} = -5V, I_C = -2mA
	BC857C		420	—	800		V_{CE} = -5V, I_C = -2mA
Collector-Emitter Saturation Voltage (Note 8)		$V_{CE(sat)}$	—	—	-300	mV	I_C = -10mA, I_B = -0.5mA
			—	—	-650		I_C = -100mA, I_B = -5mA
Base-Emitter Turn-on Voltage (Note 8)		$V_{BE(on)}$	-600	—	-750	mV	V_{CE} = -5V, I_C = -2mA
			—	—	-820		V_{CE} = -5V, I_C = -10mA
Base-Emitter Saturation Voltage (Note 8)		$V_{BE(sat)}$	—	-700	—	V	I_C = -10mA, I_B = -0.5mA
			—	-850	—		I_C = -100mA, I_B = -5mA
Transition Frequency		f_T	100	—	—	MHz	V_{CE} = -5V, I_C = -10mA, f = 100MHz
Output (Collector) Capacitance		C_{obc}	—	2	—	pF	V_{CB} = -10V, f = 1MHz
Output (Emitter) Capacitance		C_{oec}	—	10	—	pF	V_{EB} = -0.5V, f = 1MHz
Noise Figure		NF	—	—	10	dB	V_{CE} = -5V, I_C = -200µA, R_S = 2kΩ, f = 1kHz BW=200Hz

Note: 8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

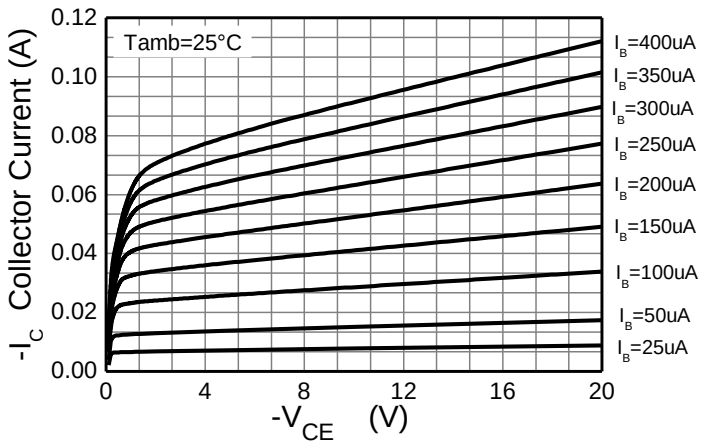


Fig.5 I_C v V_{CE}

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

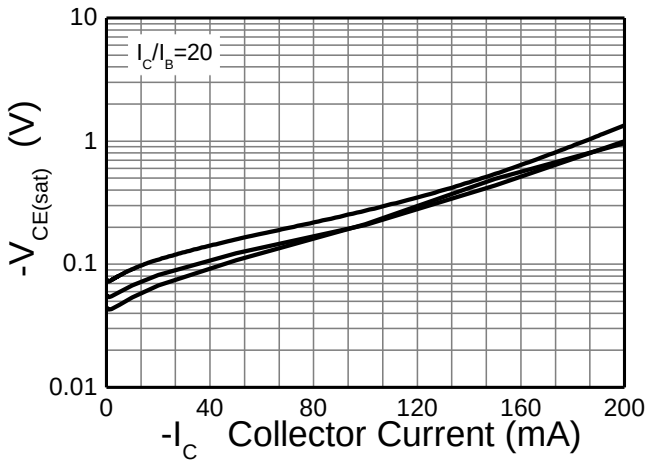


Fig.6 $V_{CE(sat)}$ v I_C

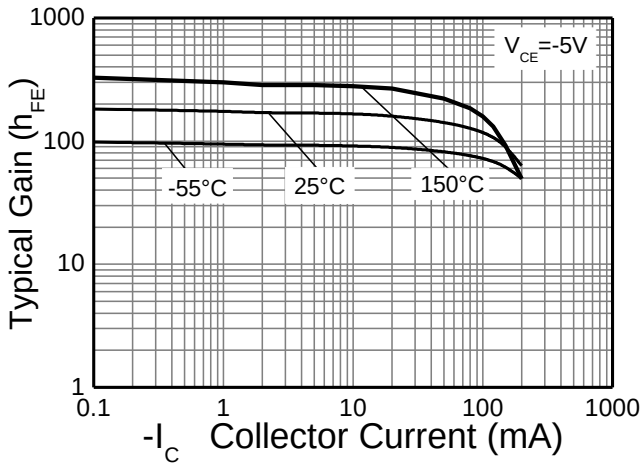


Fig.7 h_{FE} v I_C (A Band)

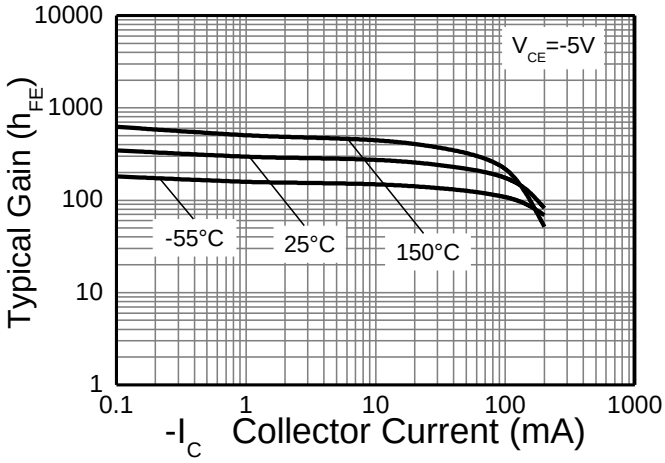


Fig.8 h_{FE} v I_C (B Band)

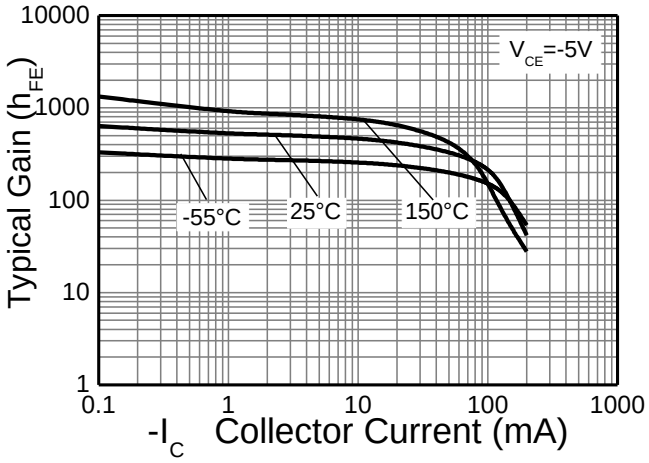


Fig.9 h_{FE} v I_C (C Band)

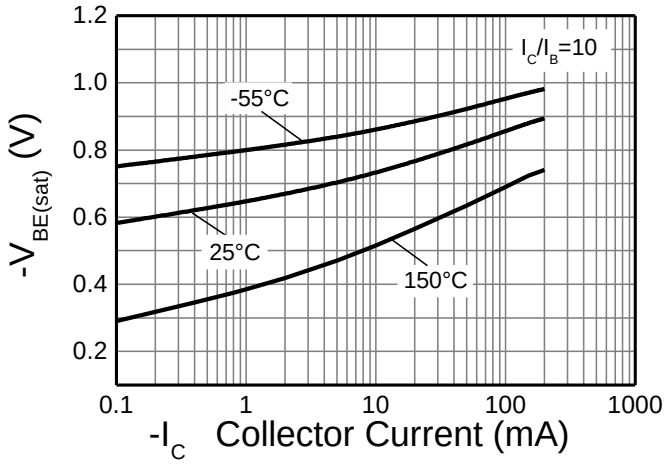


Fig.10 $V_{BE(sat)}$ v I_C

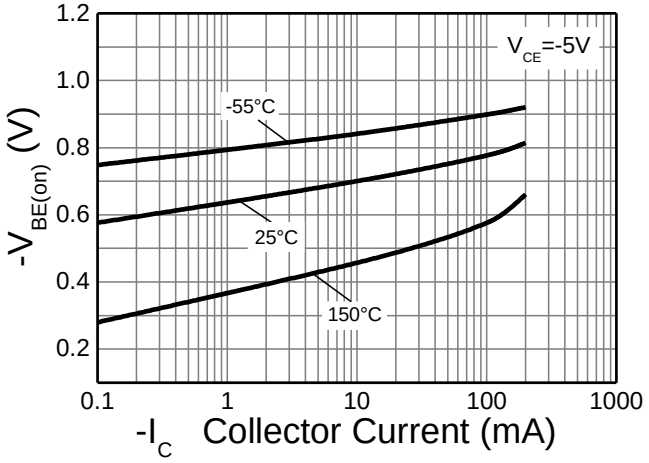
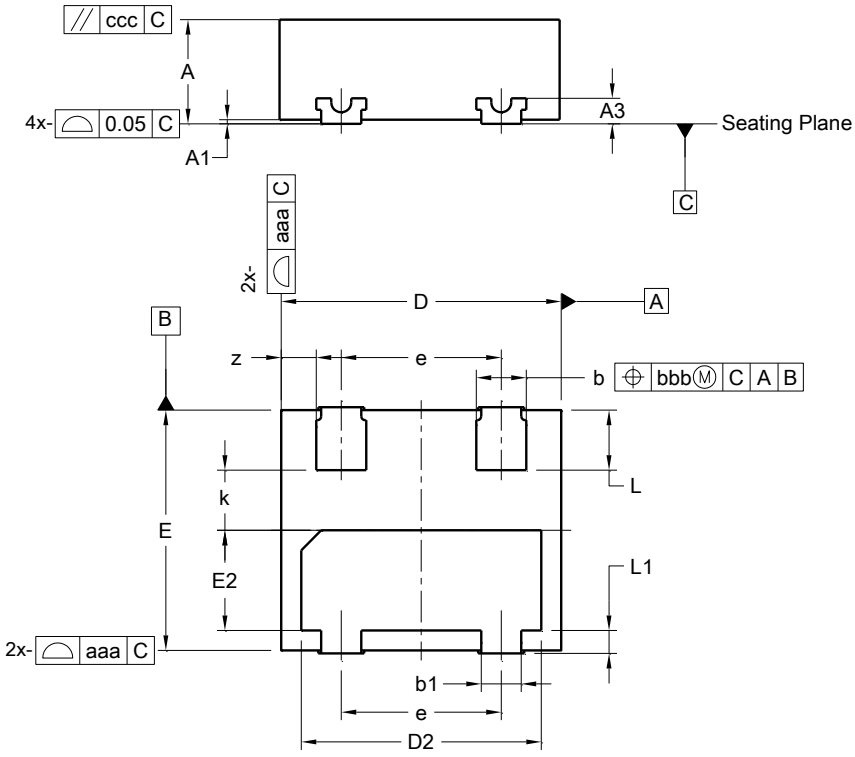


Fig.11 $V_{BE(on)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1412-3/SWP (Type A)



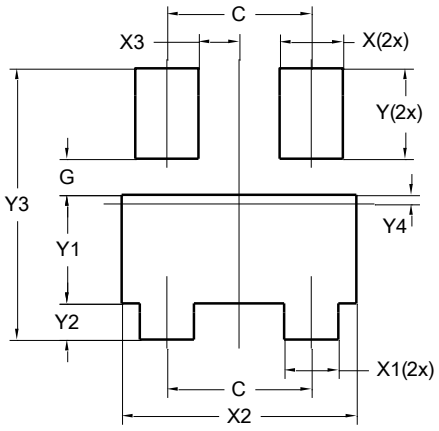
U-DFN1412-3/SWP (Type A)			
Dim	**Min**	**Max**	**Typ**
A	0.47	0.57	0.52
A1	0.00	0.05	0.03
A3	–	–	0.127
b	0.22	0.30	0.25
b1	0.15	0.25	0.20
D	1.35	1.45	1.40
D2	1.17	1.25	1.20
e	0.80 BSC		
E	1.15	1.25	1.20
E2	0.47	0.55	0.50
k	–	–	0.30
L	0.25	0.35	0.30
L1	0.065	0.165	0.115
z	–	–	0.175
aaa	0.25		
bbb	0.10		
ccc	0.10		
All Dimensions in mm			

Note: 9. Side wall tin plated package for wettable flanks in AOI.

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1412-3/SWP (Type A)



Dimensions	Value (in mm)
C	0.800
G	0.200
X	0.350
X1	0.300
X2	1.300
X3	0.225
Y	0.500
Y1	0.600
Y2	0.200
Y3	1.500

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